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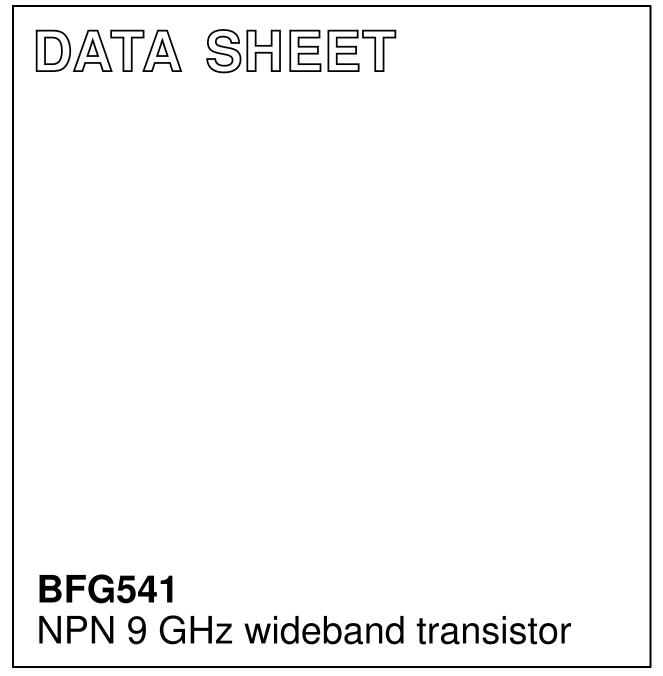


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DISCRETE SEMICONDUCTORS



Product specification

September 1995



FEATURES

• High power gain

- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability.

DESCRIPTION

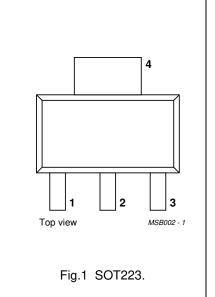
NPN silicon planar epitaxial transistor, intended for wideband applications in the GHz range, such as analog and digital cellular telephones, cordless telephones (CT1, CT2, DECT, etc.), radar detectors, satellite TV tuners (SATV), MATV/CATV amplifiers and repeater amplifiers in fibre-optic systems.

The transistors are mounted in a plastic SOT223 envelope.

PINDESCRIPTION1emitter2base

3 emitter 4 collector

PINNING



Product specification

BFG541

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------------------|---------------------------------------|---|------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | - | - | 20 | V |
| V _{CES} | collector-emitter voltage | R _{BE} = 0 | _ | _ | 15 | V |
| I _C | DC collector current | | _ | _ | 120 | mA |
| P _{tot} | total power dissipation | up to $T_s = 140 \text{ °C}$; note 1 | - | - | 650 | mW |
| h _{FE} | DC current gain | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; T_{j} = 25 \text{ °C}$ | 60 | 120 | 250 | |
| C _{re} | feedback capacitance | $I_{C} = 0; V_{CB} = 8 V; f = 1 MHz$ | _ | 0.7 | - | pF |
| f _T | transition frequency | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 1 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$ | _ | 9 | - | GHz |
| G _{UM} | maximum unilateral power gain | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ | - | 15 | - | dB |
| | | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 2 \text{ GHz};$ $T_{amb} = 25 \text{ °C}$ | - | 9 | - | dB |
| S ₂₁ ² | insertion power gain | $I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ | 13 | 14 | - | dB |
| F | noise figure | $\label{eq:Gamma} \begin{array}{l} \Gamma_{\text{s}} = \Gamma_{\text{opt}}; \ \text{I}_{\text{C}} = 10 \ \text{mA}; \ \text{V}_{\text{CE}} = 8 \ \text{V}; \\ \text{f} = 900 \ \text{MHz}; \ \text{T}_{\text{amb}} = 25 \ ^{\circ}\text{C} \end{array}$ | _ | 1.3 | 1.8 | dB |
| P _{L1} | output power at 1 dB gain compression | $ I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; R_{L} = 50 \Omega; $ | - | 21 | - | dBm |
| ITO | third order intercept point | $\label{eq:lc} \begin{array}{l} I_C = 40 \text{ mA}; V_{CE} = 8 \text{V}; \text{R}_L = 50 \Omega; \\ \text{f} = 900 \text{MHz}; \text{T}_{\text{amb}} = 25 ^\circ\text{C} \end{array}$ | _ | 34 | - | dBm |

LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|---------------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | - | 20 | V |
| V _{CES} | collector-emitter voltage | R _{BE} = 0 | - | 15 | V |
| V _{EBO} | emitter-base voltage | open collector | - | 2.5 | V |
| I _C | DC collector current | | _ | 120 | mA |
| P _{tot} | total power dissipation | up to $T_s = 140 \text{ °C}$; note 1 | _ | 650 | mW |
| T _{stg} | storage temperature | | -65 | 150 | °C |
| Tj | junction temperature | | - | 175 | °C |

THERMAL RESISTANCE

| SYMBOL | PARAMETER | CONDITIONS | THERMAL RESISTANCE |
|---------------------|---|---------------------------------------|--------------------|
| R _{th j-s} | thermal resistance from junction to soldering point | up to $T_s = 140 \text{ °C}$; note 1 | 55 K/W |

Note

1. T_s is the temperature at the soldering point of the collector tab.

BFG541

CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------------------|---|--|------|------|------|------|
| I _{CBO} | collector cut-off current | $I_{E} = 0; V_{CB} = 8 V$ | - | - | 50 | nA |
| h _{FE} | DC current gain | I _C = 40 mA; V _{CE} = 8 V | 60 | 120 | 250 | |
| Ce | emitter capacitance | $I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$ | - | 2 | _ | pF |
| C _c | collector capacitance | $I_E = i_e = 0; V_{CB} = 8 V; f = 1 MHz$ | - | 1 | - | pF |
| C _{re} | feedback capacitance | $I_{C} = 0; V_{CB} = 8 V; f = 1 MHz$ | - | 0.7 | _ | pF |
| f _T | transition frequency | I_{C} = 40 mA; V_{CE} = 8 V; f = 1 GHz; T_{amb} = 25 °C | - | 9 | _ | GHz |
| G _{UM} | maximum unilateral power gain (note 1) | I_{C} = 40 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C | - | 15 | _ | dB |
| | | $\label{eq:lc} \begin{array}{l} I_C = 40 \text{ mA}; V_{CE} = 8 \text{V}; \text{f} = 2 \text{GHz}; \\ T_{amb} = 25 ^\circ\text{C} \end{array}$ | - | 9 | - | dB |
| S ₂₁ ² | insertion power gain | $I_c = 40 \text{ mA}; V_{CE} = 8 \text{ V}; f = 900 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ | 13 | 14 | - | dB |
| F | noise figure | $\Gamma_{s} = \Gamma_{opt}$; I _C = 10 mA; V _{CE} = 8 V; f = 900 MHz; T _{amb} = 25 °C | - | 1.3 | 1.8 | dB |
| | | $ \Gamma_{s} = \Gamma_{opt}; I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}; $ f = 900 MHz; T _{amb} = 25 °C | - | 1.9 | 2.4 | dB |
| | | $\Gamma_{s} = \Gamma_{opt}$; I _C = 10 mA; V _{CE} = 8 V; f = 2 GHz; T _{amb} = 25 °C | - | 2.1 | - | dB |
| P _{L1} | output power at 1 dB gain compression | I_c = 40 mA; V _{CE} = 8 V; R _L = 50 Ω; f = 900 MHz; T _{amb} = 25 °C | - | 21 | - | dBm |
| ITO | third order intercept point | note 2 | - | 34 | - | dBm |
| Vo | output voltage | note 3 | _ | 500 | - | mV |
| d ₂ | second order intermodulation distortion | note 4 | - | -50 | _ | dB |

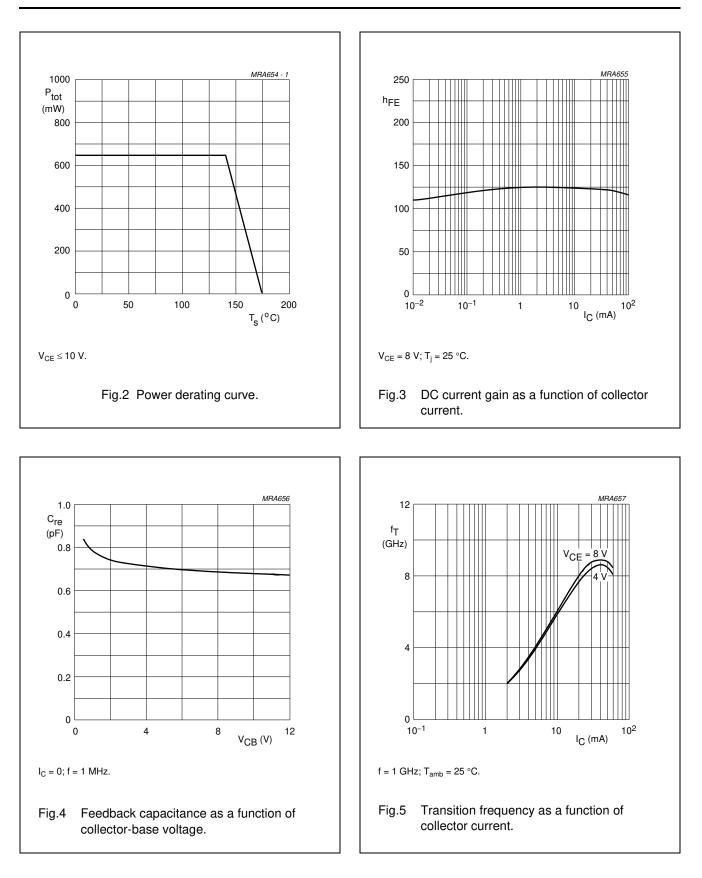
Notes

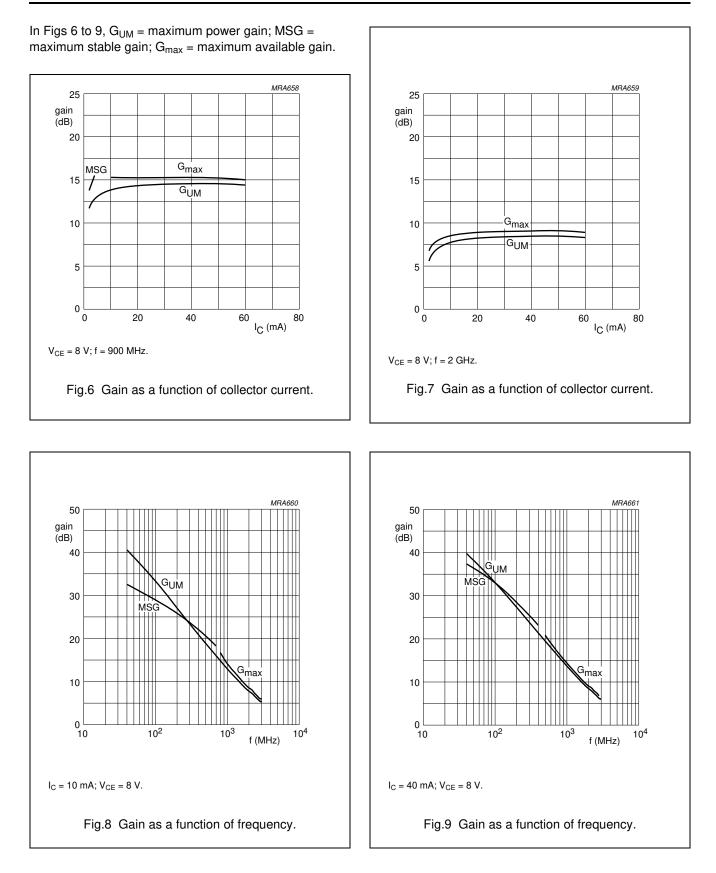
1. G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and

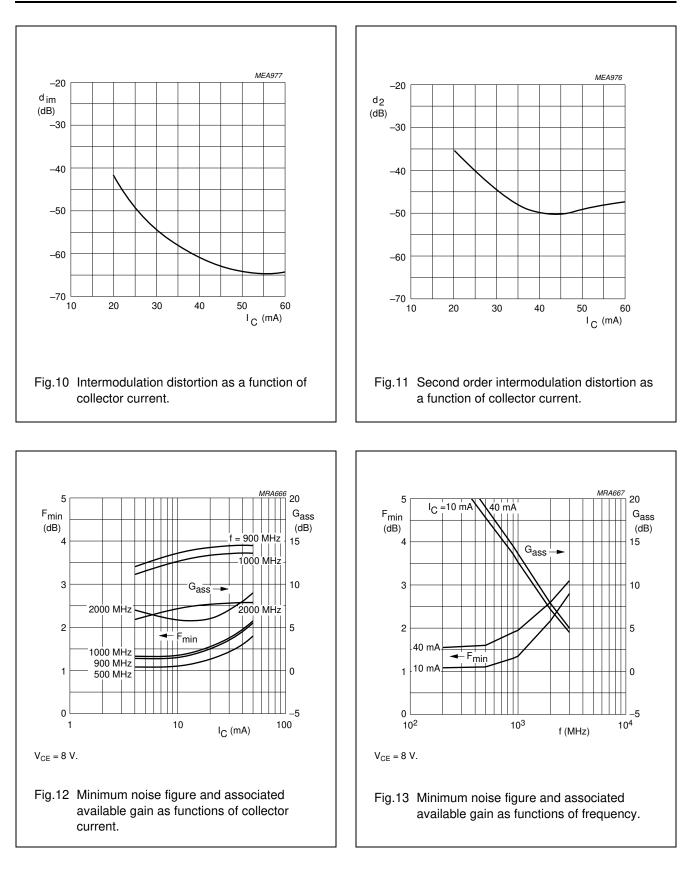
$$G_{UM} = 10 \log \frac{\left|S_{21}\right|^2}{(1 - \left|S_{11}\right|^2)(1 - \left|S_{22}\right|^2)} \, dB.$$

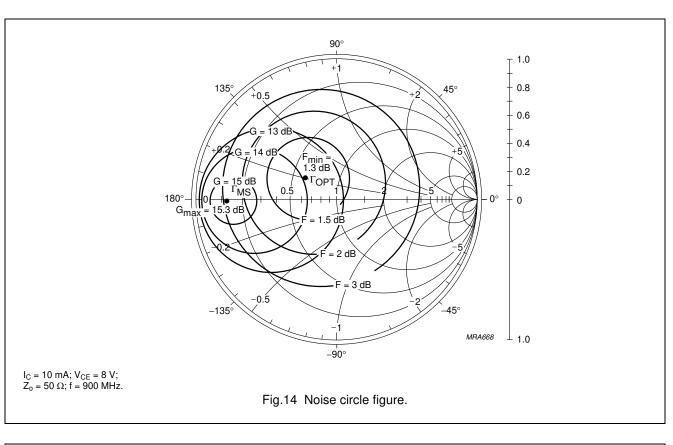
- 3. $d_{im} = -60 \text{ dB} \text{ (DIN 45004B)}; I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}; Z_L = Z_s = 75 \Omega; T_{amb} = 25 \text{ °C};$ $V_p = V_o; V_q = V_o - 6 \text{ dB}; V_r = V_o - 6 \text{ dB};$ $f_p = 795.25 \text{ MHz}; f_q = 803.25 \text{ MHz}; f_r = 805.25 \text{ MHz};$ measured at $f_{(p+q-r)} = 793.25 \text{ MHz}$
- $\begin{array}{ll} \text{4.} & I_C = 40 \text{ mA}; \text{ } V_{CE} = 8 \text{ } V; \text{ } V_o = 325 \text{ } \text{mV}; \text{ } T_{amb} = 25 \ ^\circ\text{C}; \\ & f_p = 250 \text{ } \text{MHz}; \text{ } f_q = 560 \text{ } \text{MHz}; \\ & \text{measured at } f_{(p+q)} = 810 \text{ } \text{MHz} \end{array}$

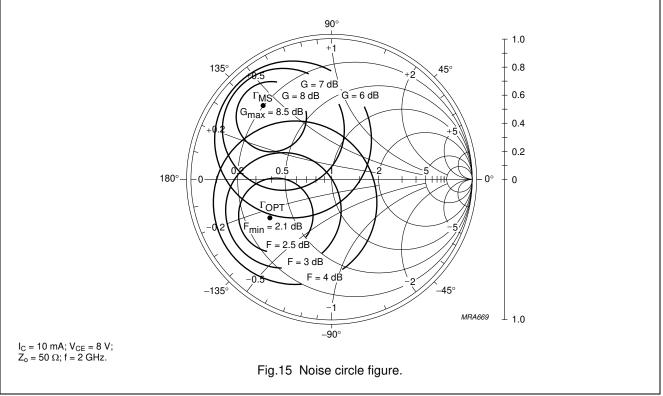
September 1995

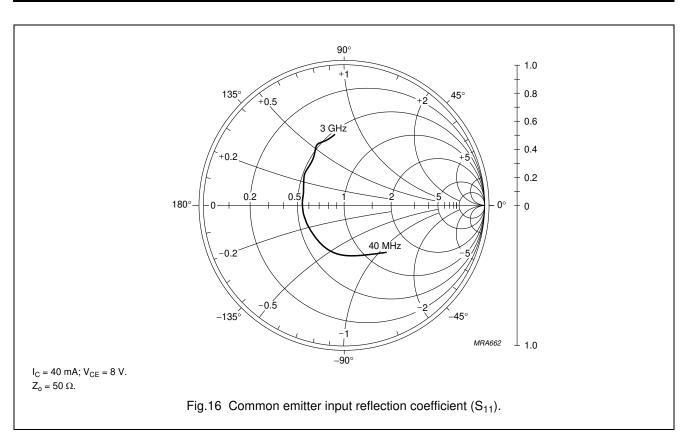


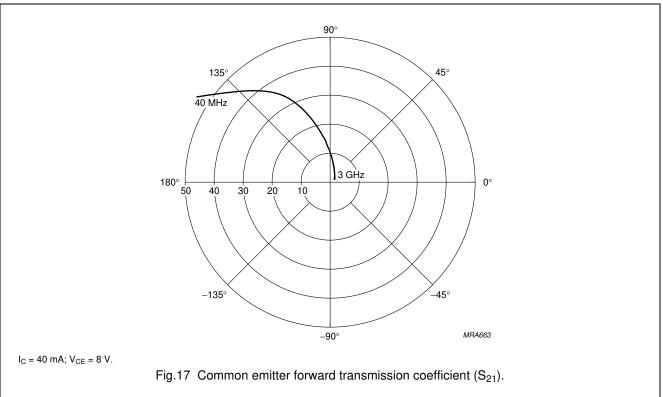


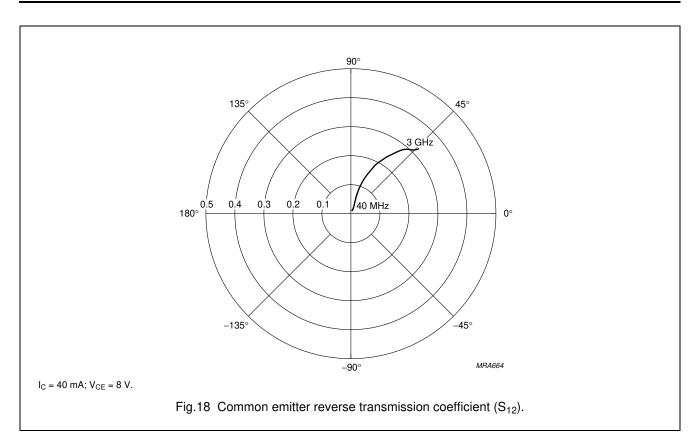


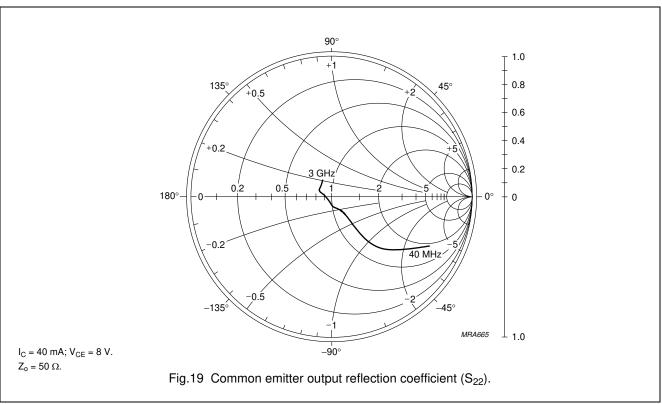




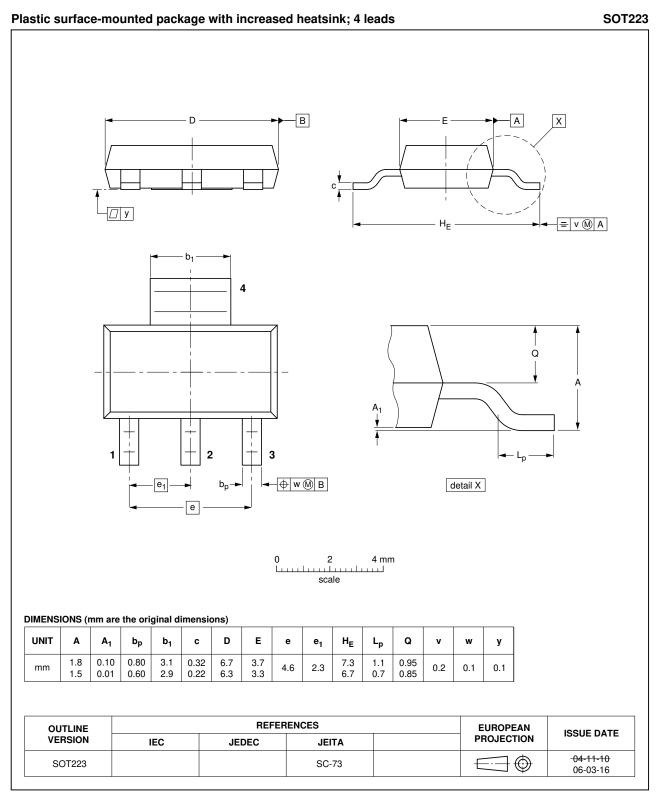








PACKAGE OUTLINE



BFG541

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

Notes

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